New U.S. Application

Attorney Docket No.: 543822004800

AMENDMENTS TO THE CLAIMS

Please amend the claims as follows.

, 1

(Original) A system (1) comprising
first semiconductor device (2a), and
second semiconductor device (2b),
wherein the first semiconductor device (2a) comprises a voltage supply means (3a),
characterized in that said voltage supply means (3a) of said first semiconductor device
(2a) is connected to said second semiconductor device (2b), so that said voltage supply means
(3a) of said first semiconductor device (2a) can provide a supply voltage for said second
semiconductor device (2b).

- 2. (Original) The system (1) according to claim 1, wherein said first semiconductor device (2a) and said second semiconductor device (2b) are arranged in the same housing (4).
- 3. (Original) The system (1) according to claim 2, wherein said first and second semiconductor devices (2a, 2b) are arranged in said housing (4) in a stacked manner.
- 4. (Currently Amended) The system (1) according to elaims 2-or 3, claim 2, wherein said housing (4) is a plug mountable semiconductor device housing.
- 5. (Original) The system (1) according to claim 4, wherein said plug mountable semiconductor device housing is a Dual-In-Line (DIL) housing.
- 6. (Original) The system (1) according to claim 4, wherein said plug mountable semiconductor device housing is a Pin-Grid-Array (PGA) housing.
- 7. (Currently Amended) The system (1) according to claims 2 or 3, claim 2, wherein said housing (4) is a surface mountable semiconductor device housing.

New U.S. Application

Attorney Docket No.: 543822004800

8. (Currently Amended) The system (1) according to any of the preceding claims claim 1, said system comprising one or several further semiconductor devices.

- 9. (Original) The system (1) according to claim 8, wherein said one or said several further semiconductor device(s) is/are arranged in the same housing (4), in particular in the same semiconductor device housing, as are said first and said second semiconductor devices (2a, 2b).
- 10. (Currently Amended) The system according to elaims 8 or 9, claim 8, wherein said voltage supply means (3a) of said first semiconductor device (2a) is additionally also connected to said one or to said several further semiconductor device(s), so that said voltage supply means (3a) of said first semiconductor device (2a) can additionally provide a supply voltage for said one or said several further semiconductor device(s).
- 11. (Currently Amended) The system (1) according to any of claims 8 or 9, claim 8, wherein said first semiconductor device (2a) comprises a further voltage supply means that is connected to said one or said several further semiconductor device(s), so that said further voltage supply means of said first semiconductor device (2a) can provide a supply voltage for said one or said several further semiconductor device(s).
- 12. (Currently Amended) The system (1) according to any of the preceding claims, claim 1, wherein said first and/or said second semiconductor devices (2a, 2b), and/or said one and/or said several further semiconductor devices are memory devices.
- 13. (Original) The system (1) according to claim 12, wherein said memory device is a table memory device or said memory devices (2a, 2b) are table memory devices, respectively.
- 14. (Original) The system (1) according to claim 13, wherein said table memory device is a RAM table memory device or said table memory devices are RAM table memory devices, respectively.

New U.S. Application Attorney Docket No.: 543822004800

- 15. (Original) The system (1) according to claim 14, wherein said RAM table memory device is a DRAM table memory device or said RAM table memory devices are DRAM table memory devices, respectively.
- 16. (Original) The system (1) according to claim 13, wherein said table memory device is a ROM table memory device or said table memory devices are ROM table memory devices, respectively.
- 17. (Original) The system (1) according to claim 12, wherein said memory device is a functional memory device or said memory devices are fundamental memory devices, respectively, in particular PLDs and/or PLAs.
- 18. (Currently Amended) The system (1) according to any of the preceding claims, claim 1, wherein said voltage supply means (3a) and/or said further voltage supply means provide a voltage supply for said first semiconductor device (2a).
- 19. (Currently Amended) The system (1) according to any of the preceding claims, claim 1, wherein said voltage supply means (3a) and/or said further voltage supply means generate(s) the respective supply voltage from an external voltage.
- 20. (Currently Amended) The system (1) according to any of the preceding claims, claim 1, wherein said voltage supply means (3a) and/or said further voltage supply means are or comprise a voltage regulating means.
- 21. (Currently Amended) The system (1) according to any of the preceding claims claim 1, wherein said voltage supply means (3a) and/or said further voltage supply means are or comprise a charge pump.
- 22. (Currently Amended) The system (1) according to any of the preceding claims, claim 1, wherein said second semiconductor device (2b) comprises a voltage supply means (3b), and

wherein, in a first operating mode of said second semiconductor device (2b), said voltage supply means (3b) of said second semiconductor device (2b) provides the supply voltage for said second semiconductor device (2b), and wherein, in a second operating mode of said second semiconductor device (2b), said voltage supply means (3a) of said first semiconductor device (2a) provides the supply voltage for said second semiconductor device (2b).

- 23. (Original) The system (1) according to claim 22, wherein said voltage supply means (3b) of said second semiconductor device (2b) is activated in the first operating mode, and wherein said supply voltage means (3b) of said second semiconductor device (2b) is deactivated in the second operating mode.
- 24. (Currently Amended) The system (1) according to elaims 22 or 23, claim 22, wherein the second operating mode is a standby mode.
- 25. (Currently Amended) The system (1) according to claims 22, 23, or 24, claim 22, wherein the second operating mode is a refresh mode.
- 26. (Currently Amended) The system (1) according to any of claims 22 to 25, claim 22, wherein the first operating mode is a working mode, in particular a mode in which external access to the second semiconductor device (2b) is performed.
- 27. (Currently Amended) The system (1) according to any of the preceding claims, claim 1, wherein a device function adjusting means, in particular an appropriate fuse, is provided on said first and/or second semiconductor device(s) (2a, 2b), by means of which it is determined whether the corresponding semiconductor device (2a, 2b) is to assume the function of said first semiconductor device (2a) or the function of said second semiconductor device (2b).
- 28. (Currently Amended) The system (1) according to any of the preceding claims, claim 1, wherein said voltage supply means (3a) of said first semiconductor device (2a) is connected to a corresponding pad (5a) of said first semiconductor device (2a).

New U.S. Application

Attorney Docket No.: 543822004800

29. (Original) The system (1) according to claim 28, wherein said pad (5a) of said first semiconductor device (2a) is connected to a corresponding pad (5b) of said second semiconductor device (2b), in particular to a pad (5b) which said voltage supply means (3b) of said second semiconductor device (2b) can be connected to.

- 30. (Original) The system (1) according to claim 29, wherein said pad (5a) of said first semiconductor device (2a) is connected directly to the corresponding pad (5b) of said second semiconductor device (2b), in particular by means of an appropriate bonding wire (6).
- 31. (Original) The system (1) according to claim 29, wherein said pad (5a) of said first semiconductor device (2a) is connected indirectly to the corresponding pad (5b) of said second semiconductor device (2b), in particular via an interposer (9).